

**In the claims:**

1. (previously presented) An apparatus for testing a semiconductor die which comprises:

- (a) a package having a cavity therein;
- (b) a plurality of terminals in said package disposed at the periphery of said cavity;
- (c) a semiconductor die to be tested having a plurality of bond pads thereon, said die disposed in said cavity;
- (d) an interconnecting layer having electrically conductive paths thereon disposed in said cavity, each of said paths having first and second spaced apart regions thereon, said first region of each path being aligned with and contacting a said bond pad, said first region including a compliant bump probe tip having a first predetermined height above said layer and further including a standoff on said layer having a second predetermined height above said layer less than said first height; and
- (e) an interconnection between said second spaced apart region of each of said paths and one of said plurality of terminals.

2. (previously presented) The apparatus of claim 1 wherein said second spaced apart region of each of said paths is a bump aligned with and contacting one of said plurality of terminals.

3. (previously presented) The apparatus of claim 1 further including a compliant layer disposed over said interconnecting layer and providing a force causing engagement of at least said first spaced apart regions and said bond pads.

4. (previously presented) The apparatus of claim 2 further including a compliant layer disposed over said interconnecting layer and providing a force causing engagement of at least said first spaced apart regions and said bond pads.

5-8 (canceled\_

9. (previously presented) An interconnecting layer for use in a semiconductor package which comprises;

(a) an electrically insulating layer;

(b) electrically conductive paths on said layer, each of said paths having first and second spaced apart regions thereon, said second spaced apart region of each of said paths having a compliant bump having a height greater than all other structures on said layer; and

(c) a standoff disposed on said layer and having a height above said layer and less than said bump.

10. (previously presented) The layer of claim 9 wherein said second region is a bump extending above the level of said electrically conductive path.

11-12 (canceled)

13. (previously presented) The layer of claim 9 wherein said layer is flexible.

14. (previously presented) The layer of claim 10 wherein said layer is flexible.

15-21 (canceled)

22. (previously presented) An apparatus adaptable for the testing of semiconductor devices comprising:

a package; and

an interconnecting medium contained within said package having electrical paths adaptable for coupling to test circuitry, wherein said interconnecting medium includes a medium surface, a plurality of standoffs affixed to said medium surface, and a plurality of probe tips affixed to said medium surface, said probe tips adaptable for making electrical contact with pads on said semiconductor device, wherein said probe tips are compliant bump probe tips.

23. (previously presented) The apparatus of claim 22, said package further comprising:

a package base having an upper surface adapted to receive said interconnecting medium, said medium having a medium lower surface;

a bonding layer interposed between said medium lower surface and said package base upper surface; and

a package lid having a lower surface adapted to receive said semiconductor device, wherein said package lid is positioned above said package base.

24. (previously presented) The apparatus of claim 23, wherein said bonding layer is comprised of an elastomeric material.

25. (previously presented) The apparatus of claim 23, wherein said semiconductor device is a die having an upper surface, said upper surface fixed to said package lid lower surface by a bonding layer interposed therebetween.

26. (previously presented) The apparatus of claim 23, wherein said semiconductor device is a wafer having an upper surface, said upper surface fixed to said package lid lower surface by a bonding layer interposed therebetween.

27. (currently amended) The apparatus of claim 26 4, wherein said bonding layer interposed between said die and said package lid lower surface is comprised of an elastomeric material.

28. (canceled)

29. (previously presented) The apparatus of claim 22, wherein the compliant bump probe tips are comprised of a solid material.

30. (previously presented) An apparatus adaptable for the testing of semiconductor devices comprising:

a package, wherein said package has a package lid having a lower surface adapted for receiving said semiconductor device, said semiconductor device having an upper surface, and a package base having an upper surface;

an interconnecting medium contained within said package, wherein said interconnecting medium has electrical paths adaptable for coupling to test circuitry, said medium including a medium surface, said medium surface having a plurality of probe tips affixed thereto, a plurality of standoffs affixed thereto, and a lower surface, wherein said probe tips are adaptable for making electrical contact with pads on said semiconductor device and are compliant bump probe tips;

a bonding layer comprising an elastomeric material interposed between said package lid lower surface and said semiconductor device upper surface; and

a bond layer comprising an elastomeric material interposed between said interconnecting medium lower surface and said package base upper surface, said package base being adapted for receiving said interconnecting medium.

31. (previously presented) The apparatus of claim 30, wherein the compliant bump probe tips are comprised of a solid material.

32. (new) The apparatus of claim 5, wherein said bonding layer interposed between said die and said package lid lower surface is comprised of an elastomeric material.